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2    **Gas-mediated trace element incorporation into rhyolite-hosted topaz: a synchrotron**

3    **microbeam XAS study**

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9    **ABSTRACT**

10    Magmatic gas exsolving during late-stage cooling of shallow magmas has been considered an

11    important facilitator of low-pressure alteration and metal transport. However, the chemical

12    properties of such gas, particularly its metal transport mechanisms and capacity, remain elusive.

13    Trace elements in minerals produced by gas-mediated surface reaction or precipitation from gas

14    capture details of gas composition and reaction pathways. However, interpretation of mineral

15    trace element contents is dependent on understanding crystallographic controls on gas/mineral

16    partitioning. This work investigates the structural accommodation of As, Mn, Ga, Ge, Fe, and Ti

17    in vapor-deposited topaz of vesicular topaz rhyolite from the Thomas Range, Utah, through

18    single-crystal synchrotron microbeam X-ray techniques on picogram quantities of those trace

19    elements. X-ray absorption near edge structure (XANES) data indicates that these elements are

20    incorporated into topaz as $As^{5+}$, $Fe^{3+}$, $Mn^{3+}$, $Ti^{4+}$, $Ga^{3+}$, and $Ge^{4+}$. Extended X-ray absorption fine

21    structure (EXAFS) analysis for these trace elements, compared to EXAFS of structural Al and

22    Si, reveals that $As^{5+}$ and $Ge^{4+}$ are incorporated directly into the tetrahedral site of the topaz

23   structure, with the octahedral site accommodating $Mn^{3+}$, $Fe^{3+}$, $Ga^{3+}$, and $Ti^{4+}$. For $As^{5+}$ and $Fe^{3+}$,

24   the structural impact of substitution extends to at least second neighbors (other elements were

25   only resolvable to first neighbors). Further interpretation of the EXAFS results suggests that the

26   substitution of $Ti^{4+}$ results in increased distortion of the octahedral site, while the other trace

27   elements induce more uniform expansion correlating in magnitude to their ionic radius.

28   Comparison of quantified X-ray fluorescence (XRF) data for two topaz crystals from this

29   rhyolite reveals variable trace element concentrations for $As^{5+}$, $Fe^{3+}$, $Ga^{3+}$, and $Ti^{4+}$, reflective of

30   a source gas undersaturated in these trace elements changing in concentration over the period of

31   topaz deposition. The identical $Ge^{4+}$ content of the two topaz crystals suggests that $Ge^{4+}$ in the

32   gas was buffered by the growth of another $Ge^{4+}$-bearing phase, such as quartz. The very low

33   $Mn^{3+}$ content in the topaz crystals does not reflect the abundance of $Mn^{3+}$ in the gas (saturation of

34   Mn is evidenced by coexisting bixbyite). Instead, it suggests a strong Jahn-Teller inhibitory

35   effect to the substitution of $Mn^{3+}$ for $Al^{3+}$ in the distorted octahedral site of topaz. It is proposed

36   that exsolution of an HF-enriched gas from cooling rhyolitic magma led to local scouring of Al,

37   Si, and trace metals from the magma. Once topaz crystals nucleated, self-catalyzed reactions that

38   recycle HF led to continued growth of topaz.

39      KEYWORDS: crystal structure, EXAFS, igneous rocks, magmatic gas, rhyolite, silicates,

40   single-crystal EXAFS, topaz, trace elements, vapor phase, X-ray absorption spectroscopy

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## INTRODUCTION

48     Topaz, $Al_2SiO_4(F,OH)_2$, is associated with shallow intrusive domes and lava flows of F-rich

49     rhyolite, specifically, the "topaz rhyolites" of the extensional regions of western North America

50     (e.g., Burt et al. 1982). It is also found in similar rocks cooled at deeper levels, such as rare-earth

51     element enriched pegmatites (e.g., Goad and Černy 1981; Groat et al. 2014) and the plutonic

52     ongonites of eastern Russia and Mongolia (e.g., Kovalenko and Kovalenko 1976). These rocks

53     share the characteristics of high Si, Fe/Mg, and alkali contents; low Ti, Mg, Ca, and P contents;

54     mildly peraluminous character; substantial enrichment of Rb, Cs, Nb, Y, U, Th, Ta, and HREE;

55     and depletion of Eu, Sr, and Co (e.g., Christiansen et al. 1984). Recognition of spatial and

56     genetic links between topaz rhyolite vent complexes and volcanogenic deposits of Be, Li, U, and

57     F (e.g., Lindsey 1977; Bikun 1980; Burt and Sheridan 1981), subvolcanic breccia, porphyry, and

58     greisen deposits of Mo, W, and Sn (e.g., Burt et al. 1982), and F- and Mn-rich base and precious

59     metal veins in volcanic rocks (Bove et al. 2007) (or F-rich skarn replacements in carbonate

60     rocks) make these rhyolites of particular importance.

61     Topaz of nearly F-endmember composition is found in isolated gas cavities and gas vent

62     channels within topaz rhyolites (e.g., Burt et al. 1982). Textural relationships suggest that vapor

63     played an integral role in topaz formation as well as in the formation of the associated quartz,

64     bixbyite, hematite, pseudobrookite, spessartine-almandine garnet, Mn-rich beryl, and cassiterite

65     (e.g., Holfert 1978; Christiansen et al. 1980). The unusual nature of this mineral assemblage, its

66     prevalence in topaz rhyolite, and the chemistry of the rhyolite itself, all suggest that the vapor

67     was sourced from the rhyolite at shallow depths (e.g., Lipman et al. 1969). The minerals in the

68     cavities appear to have been precipitated at high temperature and low pressure (e.g. Roedder and

69  Stalder 1988) and therefore, may provide insights into F-rich magmatic gas before it has

70  undergone various scrubbing reactions and lost much of its dissolved metal load.

71      Topaz associated with topaz rhyolite is known to contain trace elements (e.g. Northrup and

72  Reeder 1994; Schott et al. 2003; Wasim et al. 2011; Breiter et al. 2013a; Agangi et al. 2014) that

73  may provide insights into the chemistry of the magmatic gas involved in topaz production.

74  Northrup and Reeder (1994), in their study of the incorporation of trace elements onto growth

75  surfaces of topaz crystals from Mexico, detected Ti, Fe, Ga, Ge, As, and Nb by synchrotron

76  microbeam X-ray fluorescence and noted that these are present in concentrations below

77  approximately 500 ppm. In topaz from an ongonite from Transbaikalia, Russia, Agangi et al.

78  (2014) detected Fe, Na, P, Li, B, Be, Nb, Ta, W, Ga, Ba, and REEs among other trace elements.

79  Both sets of workers concluded that these trace elements were not in inclusions or defects, but

80  rather incorporated into the topaz lattice. Northrup and Reeder (1994) based this conclusion on

81  the uniformity of the cathodoluminescence maps and XRF concentrations of most trace element

82  within subsectors in the crystal and their strict adherence to crystallographic controls. Agangi et

83  al. (2014) based this on smooth time-resolved LAICP-MS signals. However, none of these

84  workers were able to document the incorporation sites of the trace elements in the topaz

85  structure.

86      The topaz F-endmember, $Al_2SiO_4F_2$, is orthorhombic, with space group Pbnm. Its structure

87  (Alston and West 1928; Pauling 1928; Ribbe and Gibbs 1971) consists of zig-zag chains of edge-

88  sharing $AlO_4F_2$ octahedra along the $c$ axis with cross-linking $SiO_4$ tetrahedra (Fig. 1). Adjacent

89  chains of octahedra are rotated 90 degrees relative to each other. Each aluminum octahedron

90  shares two non-opposing O-O edges with adjoining octahedra; the four corners (oxygen ions)

91  defining these edges are also shared with tetrahedra. Fluorine atoms are on adjacent apices of

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92    each octahedron; each F is bonded to 2 Al sites to link adjacent chains (Ribbe and Gibbs 1971).

93    The octahedral site is highly distorted (see Fig. 8 in Northrup and Reeder 1994), with Al-F

94    distances ranging from 1.791 to 1.800 Å and Al-O distances ranging from 1.888 to 1.899 Å.

95    Each $SiO_4$ tetrahedron bridges across the bend of an octahedral chain along c and also cross-links

96    to two adjacent chains. These tetrahedra are somewhat distorted, with Si-O distances ranging

97    from 1.638 to 1.647 Å. Each O in this structure is coordinated to one Si and two Al sites. The

98    $SiO_4$ groups only share corners with octahedra.

99        In the topaz F-endmember, there is one Al site; however, in partially hydroxylated topaz,

100   there are three unique Al environments whose abundances depend on the relative concentrations

101   of OH and F ($[AlO_4(OH)_2]^{7-}$, $[AlO_4(F)_2]^{7-}$, and $[AlO_4OH,F]^{7-}$) (e.g. O'Bannon and Williams

102   2019). Unlike topaz from metasediments associated with subduction, which are commonly

103   hydroxylated (e.g. O'Bannon and Williams 2019), topaz associated with topaz rhyolites can be

104   assumed to be compositionally close to the F-endmember. This assumption is supported by early

105   measurements of the refractive index of vapor-deposited topaz from the Thomas Range. Penfield

106   and Minor (1894) analyzed F and $H_2O$ in topaz from the Thomas range and found that the

107   amount of water was minor and the F content was very close to that computed for stoichiometric

108   F-endmember. These workers also observed that the physical and optical properties of topaz vary

109   with the fluorine and water content. Later work by Staatz and Carr (1964) noted that all of the

110   topaz they analyzed from the Thomas Range had similar refractive indices, significantly different

111   from those of topaz associated with more water-rich magmas. Such F-rich topaz is also found in

112   ongonites (Agangi et al. 2014). The increase in F/OH ratio of topaz with formation temperature

113   (Thomas 1982) is consistent with topaz forming early during degassing of topaz rhyolite magma.

114 Northrup and Reeder (1994) and Agangi et al. (2014) speculated that because the topaz

115 structure is based on a dense packing of anions and has little room for interstitial substitution,

116 trace elements probably substitute for Si or Al. On the basis of size considerations, Northrup and

117 Reeder (1994) predicted that $Fe^{3+}$, $Ga^{3+}$, and $Mn^{3+}$ would replace $Al^{3+}$ in the topaz structure,

118 while $Ge^{4+}$ would substitute for $Si^{4+}$. Since $Ti^{4+}$ is too large for the Si tetrahedron they suggested

119 that it substitutes for $Al^{3+}$ with charge compensation occurring through substitution of $O^{2-}$ for $F^-$.

120 Similarly, they predicted that $Nb^{5+}$ would replace $Al^{3+}$ with a coupled substitution of $2O^{2-}$ for $2F^-$

121 . The complexities of As substitution are compounded by its unknown valence state in topaz.

122 Northrup et al. (1995) reported preliminary As EXAFS results on powdered topaz from a

123 Mexican topaz rhyolite and concluded that As was incorporated into topaz as tetrahedrally

124 coordinated $As^{5+}$, with an As-O distance of 1.70 (0.02) Å. However, as this was a bulk

125 measurement, they were unable to definitively identify topaz as the host of this As. Based on

126 simple charge balance considerations, Agangi et al. (2014) suggested that trace element

127 incorporation was primarily valence-based, for example, replacement of Si by other cations in

128 the 4+ oxidation state (Ti, V), and replacement of $Al^{3+}$ by 3+ cations (Ga, Fe, Mn). Uptake of

129 Nb, Ta, and W, which usually occur in the 5+ oxidation state, would require coupled

130 substitution.

131 In order to clarify the structural accommodation of As, Mn, Ga, Ge, Fe, and Ti in F-rich

132 topaz, we obtained detailed information on their crystallographic environment through

133 synchrotron-based XAFS (X-ray absorption fine structure) investigation of single-crystal topaz at

134 microbeam resolution. Data collection spanned the XANES (X-Ray Absorption Near Edge

135 Structure) and EXAFS (Extended X-ray Absorption Fine Structure) regions. XAFS probes the

136 details of how X-rays are absorbed by an atom at energies near and above the core-level binding

137   energies of that atom. The XANES region is sensitive to oxidation state and coordination

138   chemistry of the absorbing atom; the EXAFS region provides details about an element's local

139   structure (within ~10 Å) in crystalline or non-crystalline materials (e.g., the distances,

140   coordination number, and species of the neighbors of the absorbing atom, Newville 2008). For

141   this investigation, we used the hard X-ray microprobe, XFM (which accesses elements from Ca

142   to Zr using their K absorption edges and heavier elements using their L edges) and the tender-

143   energy microprobe TES (Northrup 2019) (which provides unique access to lighter elements Mg

144   through Ca) at NSLS-II; details below.

## ANALYTICAL PROCEDURE

### Sample characteristics and preparation

147        The topaz crystal studied here by XAS (Topaz-64) is from Topaz Mountain of the Thomas

148   Range, Utah. The sample is geologically young (6-7 Ma based on the age of the rhyolite;

149   Lindsey 1982). It is 4x6x24 mm in length (along the a, b, and c axes, respectively), and is

150   dominated by (110), with lesser forms (112), (002), (020), (111), (112) and (101) (Fig. 2). A

151   smaller topaz crystal (2x4x14 mm) is attached; this crystal supports a partially embedded 1mm

152   bixbyite ($Mn_2O_3$) cube. The lower part of the doubly-terminated main crystal encases concentric

153   layers of small quartz crystals and fine-grained rhyolitic matrix. The crystal is transparent with

154   large areas free from visible inclusions. It has pristine surfaces including sharply defined

155   polygonized growth hillocks, indicating the absence of fluid interaction subsequent to crystal

156   formation. Its light sherry color indicates that the crystal was not subjected to heat or exposed to

157   sunlight as either process would render it colorless (e.g., Rossman 2011). The pristine nature of

158   this crystal suggests that it preserves its original trace element budget.

159    The area chosen for analysis lies on a large (3x9 mm) polygonized growth hillock on one of

160    the (110) faces (similar to the hillocks studied by Northrup and Reeder 1994, 1995). This surface

161    has growth steps aligned along [001] and [110]. For analysis, the sample was mounted intact

162    onto a standard 2"x2" frame such that the (110) surface faced the beam at 45 degrees and was in

163    the x-y plane of the sample stage, and the $c$ axis was vertical. Initial X-ray fluorescence survey

164    maps (e.g. Fig. S1) were used to identify an area of uniform composition, free from oxide

165    inclusions that may be rich in the trace elements of interest. The volume of topaz accessed for

166    each element was defined by a beam size of ~10 μm with an effective sampling depth of 10-150

167    μm depending on incident beam and fluorescence photon energies.

168    **Beamline setup**

169    The optical setup for the XFM hard X-ray microprobe from its three-pole-wiggler broadband

170    source consists first of a horizontal toroidal focusing mirror to gather pink beam to a secondary

171    source aperture (SSA). The beam diverging from the SSA is then vertically collimated by a bent

172    flat mirror and monochromated by a fixed-exit Si(111) double-crystal monochromator. A

173    secondary microfocus is produced by use of an orthogonal pair of dynamically bent mirrors in

174    KB geometry, such that beam size at the sample can be adjusted from 2 to 10 μm by adjusting

175    the SSA size at the expense of flux. Samples are mounted on a fine-resolution x-y scanning stage

176    at 45 degrees to the incident beam, so that the sample surface can be raster-scanned with respect

177    to the fixed beam. A 4-element Si drift detector is located in the horizontal plane at 45 degrees to

178    the sample (90 degrees to the incident beam to minimize scatter) to capture fluorescence from

179    the sample. Fluorescence signal is processed by selecting element-specific fluorescence energies

180    and normalizing to incident beam intensity as measured by an ionization chamber upstream of

181    the microfocusing mirrors.

182    The optical setup at the TES tender-energy microprobe beamline (Northrup 2019), co-

183    designed as the lower-energy sister beamline to XFM at NSLS-II, consists of a bend-magnet

184    source, vertically collimating mirror pair, fixed-exit double-crystal monochromator, and

185    vertically deflecting toroidal mirror focusing to an SSA; beam diverging from the SSA is

186    refocused by a custom set of KB mirrors to a user-tunable spot size of 2 to 10 μm. The sample

187    chamber environment is helium at 1 atm pressure. Sample stage and detector geometry is the

188    same as for XFM; fluorescence is measured using a Ge detector optimized for this energy range.

189    This geometry, including the KB endstation and monochromator now at TES, was prototyped at

190    NSLS Beamline X15B. The Al EXAFS and Si EXAFS reported here were measured at X15B; Si

191    XANES and additional Si EXAFS were measured at TES. Si measurements used InSb

192    monochromator crystals; Al measurements used beryl ($Be_3Al_2Si_6O_{18}$) crystals.

193    **Data collection**

194    XRF spectra were collected and summed over selected regions of a small (100 x 100 μm)

195    area of Topaz-64, and of an additional topaz crystal from the same locality (Topaz-7), for

196    comparison with concentration standards measured under identical geometric conditions. These

197    standards are thin films of elements deposited on a polymer substrate with controlled mass per

198    unit area, so there is no thickness effect on fluorescence, only the effects of layer ordering and of

199    absorption by layers above the element of interest. Reference films used were NIST 1833 Serial

200    No. 991 for Fe and Ti, NIST 1832 Serial No. 1294 for Mn, and MicroMatter 41156 for As and

201    Ga.

202    XAS spectra for Topaz-64 were obtained by scanning incident beam energy across each

203    element's K absorption edge while measuring fluorescence (which is directly proportional to

204    absorption). Energy steps were larger in the pre-edge background and post-edge regions, and

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205     smaller over the absorption edge in order to capture edge position and detailed features of

206     XANES. For EXAFS, a longer post-edge range was measured in steps calculated in constant k.

207     EXAFS measurements of all trace elements were made in the same area of the crystal (within a

208     radius of 150 μm) and in the same geometric orientation (Table S1 in Supplementary Material

209     provides XAS scan parameters used for each element). Fresh spots within this area were used for

210     each redox-sensitive element, to minimize the chance for radiation-induced changes. Spectra

211     were also monitored scan-to-scan for any indication of progressive changes; no evidence for

212     beam-induced change was observed for any of these measurements.

213     The approach adopted here, microbeam XAS of a single crystal, was necessary to enable

214     probing of microscale regions free of inclusions, but there are drawbacks to this approach that

215     must be carefully identified and mitigated. XANES and EXAFS measurements of a single crystal

216     will be sensitive to crystal orientation relative to the horizontal polarization of the incident beam

217     (e.g. Dyar et al. 2016). All single-crystal measurements reported here were collected with the

218     crystal in the same orientation relative to the beam in order to minimize the effects of

219     orientation-dependence. The amplitude (probability of occurrence) of each individual scattering

220     path will vary with its orientation. Scattering paths oriented vertically are least represented. This

221     limitation is mitigated by the grouping of paths into shells, and into sets of shells sharing

222     parameters, as discussed below. This grouping averages over a large number of paths, providing

223     a sufficient distribution to minimize orientation effects impacting individual paths. We

224     specifically chose the orientation of the sample, with the (110) plane at 45 degrees to the beam

225     and $c$ axis vertical, because in the topaz structure that orientation gives a fairly well-averaged

226     representation of the different paths. In topaz, the crankshaft-like chains along the $c$ axis (Fig. 1)

227     effectively distribute most paths away from the vertical [001] vector. The symmetry of topaz

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228  indicates that sub-units alternate by 90 degrees in orientation perpendicular to the *c* axis, further

229  averaging the orientation effects for the chosen orientation. This averaging was confirmed by the

230  similarity between Si EXAFS of both powdered and single-crystal samples. Finally, all

231  measurements of trace elements, and the Si reference EXAFS, were done in exactly the same

232  orientation, validating the direct comparisons presented in this work.

233      For a baseline measurement of the topaz host structure, we also measured Si K-edge

234  XANES and EXAFS of the same crystal in the same orientation, utilizing a 0.5 mm diameter

235  beam in an area free from quartz inclusions (the larger area for these measurements is justified

236  because any metal oxide inclusions will not contribute to the Si signal). Because the Al content

237  limited sampling depth for Si XAS, there was no issue with self-absorption effects as might

238  otherwise occur in an "infinitely thick" sample. For the octahedral site, we measured Al K-edge

239  EXAFS of a powdered sample of F-topaz from a topaz rhyolite near Tepetates, San Luis Potosi,

240  Mexico. Measurement of Al EXAFS is challenging, and further complicated by the Al-bearing

241  beryl monochromator crystals which precluded measurement near the Al K-edge. Therefore, we

242  were only able to measure EXAFS, not XANES, and there is inherently more uncertainty in the

243  Al fitting results.

244                          **DATA PROCESSING**

245  **Trace element concentrations**

246      Quantitative trace element concentrations were obtained by comparison of XRF maps of the

247  sample and thin-film standards. For each element, fluorescence intensity of the standard was

248  corrected for attenuation and converted to mass per unit area. This value was ratioed with

249  fluorescence intensity in the sample and converted to mass per unit volume using a computed

250   sampling depth (e.g. Citrin et al. 1998) with absorption data from the CXRO tool

251   (https://henke.lbl.gov/optical_constants/atten2.html). In the absence of a reference material for

252   Ge, the concentration was computed indirectly using a standardless method in which As

253   concentration served as the effective standard. Germanium fluorescence intensity was ratioed to

254   arsenic, with corrections for sampling depth, fluorescence efficiency, and absorption by the air

255   path and detector window. The fluorescence energies of As and Ge are similar, so the corrections

256   in the Ge calculation were relatively small.

257   **µ-XAS spectra**

258   The Demeter software suite (Ravel and Newville 2005) was used to process the XAS spectra.

259   Processing started with data assessment and compilation with the Athena module. Data obtained

260   from four detector channels were recorded; however, scans from one channel were removed

261   from the As, Ga, and Ge data sets due to prominent diffraction artifacts spanning the data set.

262   Individual scans were also screened for any glitches affecting more than a few energy data

263   points, resulting in further exclusion of a handful of scans per element. After these exclusions,

264   the usable number of scans for each element was as follows: As, 102; Fe, 61; Mn, 7; Ge, 10; Ga,

265   3; Ti, 38. The set of scans for each element was then merged and any remaining minor glitches

266   edited out. Finally, pre- and post-edge (line and spline function) backgrounds were subtracted,

267   edge steps were normalized to 1, and the Fourier transform Rbkg parameter set to 0.85 or 0.8 for

268   each element based on the expected bond lengths for the substitution sites.

269   Our approach to the analysis of the µ-XAS spectra takes advantage of knowledge of the topaz

270   structure, which provides a starting model for the two candidate cation sites. Therefore, despite

271   the limitations of microbeam data quality and the complexities arising from orientation

272   dependence, we are still able to address the questions of site assignment and local distortion.

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273     **XANES.** Initial analysis of the merged XAS spectra focused on the X-ray absorption near

274     edge structure (XANES) region. The energy position of the absorption edge of a spectrum is

275     characteristic for a particular valence state of an element. Therefore, comparison of measured

276     spectra with those of materials with known valence is a straightforward diagnostic tool to

277     determine the charge of the measured element. The valence, in turn, informs preliminary

278     assignment of the cation's structural environment, in this case tetrahedral (the Si site) or

279     octahedral (Al site) coordination. For elements with multiple possible oxidation states (Fe, Mn,

280     As), the XANES region of each element's merged spectrum was compared with XANES spectra

281     of reference standards measured under appropriate similar conditions at XFM to determine their

282     oxidation state in topaz.

283     **EXAFS.** The merged spectra were input into the Artemis software module to determine the

284     effect of trace element substitutions on interatomic distances. For each trace element, baseline

285     scattering paths were calculated from trace element-free fluor-topaz crystal structure parameters

286     of Northrup et al. (1994) by the Artemis FEFF utility, with the trace element atom substituted for

287     Si or Al as the absorbing atom in the distorted tetrahedral or octahedral site, respectively. These

288     paths are equivalent to the interatomic distances between the element of interest and a nearby

289     neighbor (i.e., bond length in the case of nearest-neighbors).

290     For fitting, single-scattering paths from the trace element of interest were grouped into shells

291     of similar path length (for example, the oxygen anions of the tetrahedral site comprised one

292     shell). The geometry of the crystal was 'frozen' except for linear expansion of these paths.

293     Fitting parameters for deviation in path length compared to the baseline crystallographic model

294     ($\Delta R$), amplitude reduction ($S0^2$), and sigma squared disorder parameters ($\sigma^2$) were assigned on a

295     per-shell basis. Separate amplitude reduction variables were needed for each shell to account for

296   orientation effects arising from measurement of an oriented single crystal. It is important to note

297   that individual scattering paths were preserved, with the shell ΔR applied uniformly to each path

298   within a shell. In this way, we evaluated the overall distortion of the local structure to

299   accommodate the trace element, while significantly reducing the number of variables. This

300   simplified fitting model limits interpretation at the scale of individual bonds but is sufficient to

301   conclusively determine the crystallographic site hosting each trace element and to evaluate

302   overall structural accommodations.

303      Shells were fit sequentially, continuing outward from the absorbing atom until data quality

304   precluded further fitting. For the octahedral site, inclusion of both oxygen and fluorine paths in

305   the first shell generally yielded a better fit than treating them separately. Most fits included one

306   shell beyond the results reported here, as the overlapping contributions from the outermost shell

307   usually improved the fit of inner shells, even when the outer shell could not be well-fitted due to

308   poorly resolved data. Notes on these partial fits, as well as any special considerations for

309   individual elements, are presented in the results section for each element.

310                                          **RESULTS**

311   **Trace element abundances**

312      Table 1 shows the calculated concentration of each trace element, and corresponding mass

313   exposed to the X-ray beam. For Topaz-64, arsenic was most abundant at 327 ppm, equivalent to

314   ~12.5 pg within the sample volume analyzed, allowing for well-resolved As XAS spectra. In

315   contrast, manganese spectra were the most difficult to resolve due to a concentration of only 9

316   ppm, or ~0.1 pg in the sample volume.

317   **XAS results**

318    The merged, deglitched XAS spectra for the trace elements studied in Topaz-64 are shown

319    in Figure 3 (black spectra, XANES region) and Figure S2 (full spectra). These spectra were used

320    for XANES and EXAFS analysis.

321    **Trace element valence states determined by XANES.** The topaz trace element XANES

322    spectra were compared to reference sample spectra (Fig. 3) measured at XFM for known

323    oxidation states. The As merged spectrum absorption edge position shows a clear match to $As^{5+}$.

324    Comparison of Fe spectra suggests Fe incorporation into topaz as ferric iron. The absorption

325    edge position of the Mn merged spectrum offers the best agreement with $Mn^{3+}$, consistent with

326    the coexisting bixbyite $((Mn,Fe)_2O_3)$. No valence standards were available for Ga, Ge, or Ti.

327    Gallium and germanium are expected to be present as $Ga^{3+}$ and $Ge^{4+}$. The titanium was

328    identifiable as $Ti^{4+}$ due to the presence of a diagnostic double-peaked pre-edge feature (e.g.

329    Farges et al. 1997).

330    XANES also offers a preliminary assignment of crystallographic sites for these substituents.

331    Although oxidation state is a first-order indicator of crystallographic site, the overall shape and

332    minor features of the XANES spectra can also be indicators as they reflect differences in

333    coordination, symmetry and crystal field. For example, as can be seen in Fig. 3, the overall

334    spectral shapes of As (Fig 3a) and Ge (Fig. 3b) are very similar to that of Si (Fig. 3b inset).

335    These differ from the other XANES spectra, which are more generally similar to each other. On

336    that basis, As and Ge likely occupy the tetrahedral site, while Fe, Mn, Ti and Ga may occupy the

337    octahedral site. The pre-edge peak height of the titanium is consistent with octahedral

338    coordination (Farges et al. 1997).

339    **Impact of trace element incorporation on local bonding and geometry.** EXAFS was

340    used to definitively identify site assignments, and to assess the effect of incorporation of the trace

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341 elements studied on local bonding and geometry in the topaz structure. The first step in EXAFS

342 analysis is conversion of energy data (Fig. S2) to frequency (k), and Fourier transformation to R

343 for each element (Figs. 4, 5, 6). The position of the first-shell peak and overall combination of

344 peaks in R (radial distance uncorrected for phase shift) yield characteristic visual fingerprints for

345 tetrahedral and octahedral substitution sites in topaz. This allows provisional differentiation

346 between the tetrahedral and octahedral sites for each trace element even before fitting efforts.

347 Based on the peaks in R, the tetrahedral site contains $As^{5+}$ and $Ge^{4+}$ and the octahedral site $Mn^{3+}$,

348 $Fe^{3+}$, $Ga^{3+}$, and $Ti^{4+}$. These assignments were confirmed by attempting to fit the data to each site

349 model and ruling out the unresolvable fit for each element.

350     Extraction of interatomic distances from EXAFS data starts with the closest coordinated

351 anions (first shell) and proceeds to nearest neighbor cations (second shell) and a set of anions

352 associated with those cations (third shell) as data quality permits. For this data set, acceptable fits

353 could only be obtained out to the first or second shell, due primarily to the extremely low

354 concentrations of most elements analyzed. To improve the quality of reported fits, and because

355 we have independent knowledge of the host structure, fitting was generally carried out to one

356 shell beyond the presented results. While these outer shells could not be fully resolved, they

357 make small but significant contributions to the overall fit. In some cases, fits generated invalid

358 negative sigma squared values. As long as the values could be positive within the uncertainty,

359 however, we accepted these as a side effect of the somewhat disparate path lengths included

360 within some shells compounded by orientation dependence effects.

361     Determining the effects of trace element substitution on the topaz structure requires

362 comparing the calculated interatomic distances from the trace element of interest to its neighbors

363 with those of the unsubstituted cation (Al or Si) and its neighbors. To assist in these

364    comparisons, Si and Al EXAFS data were collected for the sample and fitted in the same manner

365    as the trace elements. Figure 4 shows the fits for Si and Al.

366    Table 2 shows the path lengths (R) from prior crystallographic data (single-crystal X-ray

367    diffraction; Northrup et al. 1994) and those computed from the Si and Al EXAFS fits. The Al

368    results are of particular note, as Al in the beryl monochromator crystals used for this energy

369    range makes this measurement extremely difficult to obtain. We believe this to be the first

370    reported Al k-edge EXAFS data for topaz. Variations in path length between the crystallographic

371    model and this EXAFS fit were minimal and within the uncertainty of the fitting parameters for

372    both Si and Al. The somewhat higher values of $\sigma^2$ (the disorder parameter) for the Al fit is to be

373    expected given the wider spread of path lengths grouped into each shell and high correlation with

374    the $SO^2$ (amplitude reduction) parameter. Low $SO^2$ values for the second shells are also not

375    unexpected and are presumed to result primarily from orientation dependence resulting from

376    taking measurements on a single crystal.

377    **Accommodation of trace elements in tetrahedral coordination.** Figure 5 shows the

378    EXAFS data and fit for arsenic. Fitting of the merged As spectrum was carried out to the third

379    shell, although only the first and second were fully resolvable. Interatomic distances between As

380    and its first and second shell neighbors increased by ~0.06 Å compared with the unsubstituted

381    model structure (Table 3).

382    The germanium dataset proved challenging due to its low concentration in the topaz and

383    fewer usable scans. Figure 6 shows R of the Ge data and fit of the first shell. A second shell was

384    incorporated into the fit calculations so that the shoulder underlying the first shell peak could be

385    accounted for. The fit generated a first shell ΔR of 0.092 Å (Table 3).

17

386    **Accommodation of trace elements in octahedral coordination.** In the octahedral site, as

387    had been observed for the Al fitting, the fits for the elements resulted in somewhat lower $S0^2$

388    values. This lends support to the suggestion that these values are predominantly a result of

389    orientation effects rather than an issue with data quality or specific to an element. Second shell

390    fits were more difficult in general; this is due to the larger spread of path lengths contained

391    within the second shell, and their substantial overlap and possible destructive interference with

392    the paths of the third shell.

393    Figure 7 shows the data and fits in R for octahedral Fe, Ga, Mn, and Ti. Iron was fitted to the

394    nearest-neighbor silicon sites (second shell) with an unresolvable third shell. Table 4 shows the

395    computed interatomic distances. The fit produced a first shell $\Delta$R of 0.086 Å and a second shell

396    $\Delta$R of 0.021 Å. The Mn fit resulted in a first shell $\Delta$R of 0.034 Å. The second shell of Mn proved

397    difficult. Gallium was fit out to the third shell, though here we limited the number of variables by

398    sharing fitting variables between the second and third shells. Only the resulting first shell is

399    reported, with a $\Delta$R of 0.022 Å.

400    The Ti fit proved uniquely challenging; a first shell fit of acceptable quality could not be

401    obtained until the shorter Ti-F paths and longer Ti-O paths were allowed to vary independently

402    of each other in $\Delta$R. This resulted in a Ti-F $\Delta$R of .042 Å and a Ti-O $\Delta$R of .113 Å, nearly

403    doubling the difference in distance between these sites compared to the aluminum and indicating

404    a substantial non-uniform distortion of the octahedron and possibly strengthening of one or both

405    bonds to the F site (the $\Delta$R is less than the increase in ionic radius from $Al^{3+}$ to $Ti^{4+}$). This is

406    consistent with substitution of O for F in one or both of these sites to satisfy the increased

407    bonding requirement and charge balance for $Ti^{4+}$. Fitting beyond the first shell was not possible,

408    likely due to compounded effects of this increased distortion of the octahedral site.

18

## TOPAZ FORMATION AND GAS CHEMISTRY

409

410     **Topaz formation.** Formation of topaz in cavities in topaz rhyolite most likely involved a

411 gas phase. The presence of gas is consistent with the cavities found in the rhyolites and the

412 observation that crystals grew away from the rock interface and toward the cavity and spiral-

413 growth hillocks formed on surfaces not in contact with the rhyolite. The most reasonable source

414 for this gas is local, that is, the rhyolitic magma itself. Topaz formation can be envisioned as

415 resulting from either (i) direct deposition from the cooling gas or (ii) localized reaction of

416 exsolved gas with the solidified or almost solidified rhyolite. Method (i) requires a significant

417 transported load in order to produce large crystals in small cavities. Considering gas density and

418 the low solubility of the gaseous species needed for topaz growth (specifically Si and Al), a large

419 flow-through volume would be needed to provide the mass of the observed crystals. Method (ii)

420 can be accomplished by exsolved gas with high HF content and low transported load through a

421 continuous cycle of local dissolution and precipitation that can temporarily mobilize species with

422 low solubility in the gas and redistribute them while retaining HF in the gas. This is supported by

423 observation of concentric etching of the host rhyolite surrounding the original cavity as

424 evidenced by residual layers of drusy quartz crystals lining the cavity, with subsequent growth of
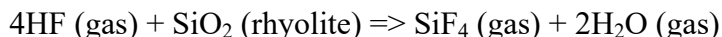
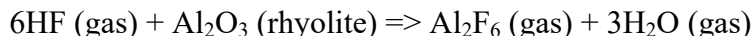425 the topaz crystal into both the cavity and the etched regions. The following reactions may define
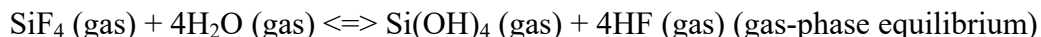
426 topaz formation:

427     $4HF \text{ (gas)} + SiO_2 \text{ (rhyolite)} => SiF_4 \text{ (gas)} + 2H_2O \text{ (gas)}$

428     $6HF \text{ (gas)} + Al_2O_3 \text{ (rhyolite)} => Al_2F_6 \text{ (gas)} + 3H_2O \text{ (gas)}$

429     $SiF_4 \text{ (gas)} + 4H_2O \text{ (gas)} <=> Si(OH)_4 \text{ (gas)} + 4HF \text{ (gas)}$ (gas-phase equilibrium)

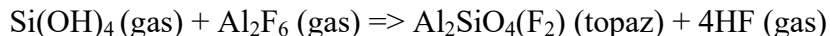430     $Si(OH)_4 \text{ (gas)} + Al_2F_6 \text{ (gas)} => Al_2SiO_4(F_2) \text{ (topaz)} + 4HF \text{ (gas)}$

19

431 Once a topaz crystal has nucleated, however, self-catalyzed surface reactions that recycle HF

432 would likely dominate. In these, –AlF on the growing surface of the topaz could react with

433 $Si(OH)_4$ (gas) to form an Al-O-Si bond and release HF. Subsequently, –SiOH on the surface

434 could react with $Al_2F_6$ (gas) and produce a Si-O-Al bond and release HF. This process could lead

435 to rapid growth of the observed large crystals of topaz in relatively small cavities.

436 The sum of the reactions given above would result in a net loss of 2HF (gas) and a net

437 production of $1H_2O$ (gas) per formula unit of topaz. This would eventually deplete the HF in the

438 gas. However, it is known that F partitions strongly into the melt in magmatic systems. Release

439 of F from the rhyolite may be limited by availability of water if HF is the primary F-bearing

440 gaseous species. Since the topaz-forming reactions produce $H_2O$, we can add the following

441 reaction to maintain HF content in the gas, as this $H_2O$ reacts with remaining F in the rhyolite:

442 $H_2O$ (gas) + $2F^-$ (rhyolite) $=>2HF$ (gas) + $O^{2-}$ (rhyolite)

443 This reaction could occur as the rhyolite is etched in the above process when temperatures are

444 still 500-700°C, and would buffer the gas $HF/H_2O$ ratio, allowing the topaz-forming reaction to

445 continue under steady-state gas composition as long as feedstock remains available and reaction

446 conditions (e.g. temperature) are maintained. One final consideration is that there is a parallel

447 reaction that produces quartz:

448 $Si(OH)_4$ (gas) $=>SiO_2$ (solid) + $2H_2O$ (gas)
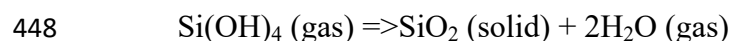
449 This reaction provides an independent mechanism to buffer the Si content in the gas, as topaz

450 crystallizes and the rhyolite feedstock is consumed.

451 **Insights into the gas.** The topaz analyzed in this study indicates that the gas involved in its

452 production was able to mobilize $As^{5+}$, $Fe^{3+}$, $Mn^{3+}$, $Ti^{4+}$, $Ga^{3+}$, and $Ge^{4+}$ in addition to Al and Si.

20

453     XANES and EXAFS analysis showed that each of these trace elements are incorporated into the

454     fluor-topaz structure, with the tetrahedral site containing $As^{5+}$ and $Ge^{4+}$ and the octahedral site

455     $Mn^{3+}$, $Fe^{3+}$, $Ga^{3+}$, and $Ti^{4+}$.

456     Although trivalent arsenic is the dominant oxidation state in basaltic glass at 1200 $^{o}$C, with

457     pentavalent As contributing less than 10% of the budget of As (Maciag and Brenan 2020), at

458     lower T and high $fO_2$, the pentavalent state is more abundant (Verweij 1980) with $As^{5+}$ species

459     such as $AsO_4^{3-}$ in the melt. If these are also prevalent in rhyolite, then in the presence of $H_2O$

460     (gas) at the surface of the rhyolite, these species may become hydrated to form $AsO(OH)_3$.

461     Studies of speciation and structure of As in natural melts and glasses suggest that such oxy-

462     hydroxide complexes form strong bonds within the rhyolite glass and solids. High HF contents

463     may be necessary to release these to the gas (e.g., Pokrovski et al. 2002; Testemale et al. 2004;

464     Borisova et al. 2010; James-Smith et al. 2010). Local transport of released $AsO(OH)_3$ and

465     precipitation of As in topaz by an HF-rich gas can be envisioned by the reaction:

466     $AsO(OH)_3$ (gas) + $Al_2F_6$ (gas) + $H_2O$ (gas) => $Al_2AsO_4(FO)$ (topaz) + 5HF (gas)
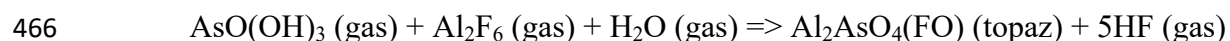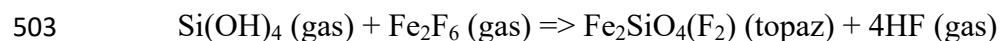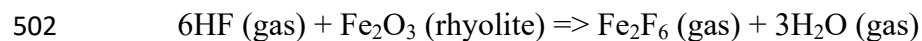
467     although it is more likely that -Al-F species on the surface of the growing topaz react with

468     $AsO(OH)_3$. This reaction reflects the coupled substitution needed for $As^{5+}$ to substitute for $Si^{4+}$ in

469     the tetrahedral site, most likely the substitution of an $O^{2-}$ for $F^-$ (or $OH^-$) at one of the two "F

470     apices" of a neighboring octahedron (Fig. 1) for charge balance. In spite of the required coupled

471     substitution, the As content (327±16 ppm) is the highest of all of the trace elements analyzed

472     here in Topaz-64 (Table 1). Arsenic contents in topaz can be quite variable, however. Table 1

473     also shows the trace element content of Topaz-7; its arsenic concentration is only 20±1 ppm.

474     This difference in As content could be explained by topaz with lower As growing earlier, since a

475     higher As content in the gas would result from continued precipitation of non-As bearing phases.

21

476    Like $As^{5+}$, $Ge^{4+}$ substitutes for Si, although its slightly greater ionic radius induces a slightly

477    greater expansion of the structure upon substitution (as indicated by the slightly longer Ge-O

478    bond relative to the As-O bond in Table 3). The similarity in size of $As^{5+}$ and $Ge^{4+}$ and their joint

479    preference for the tetrahedral site, however, suggest that their solubilities in topaz should be

480    similar. Therefore, the much lower $Ge^{4+}$ content (14.8±0.7 ppm, Topaz-64; 14.5±0.7 ppm, Topaz

481    7) compared with $As^{5+}$ content (327±16 ppm, Topaz-64) suggests several possibilities: (i) that

482    the gas may not have inherited much Ge from the rhyolite source, (ii) the $Ge^{4+}$ content of the gas

483    was being buffered by the presence of a condensed phase, leading to a concentration far below

484    saturation, or (iii) for some unknown reason, the tetrahedral site in topaz cannot accommodate

485    much $Ge^{4+}$. Breiter et al. (2013b) documented $Ge^{4+}$ contents as high as 204 ppm in topaz, that is,

486    much closer to what we observed for $As^{5+}$. This excludes (iii) and is consistent with a similar

487    partitioning potential of $As^{5+}$ and $Ge^{4+}$ into topaz. Although only 2 topaz crystals were analyzed

488    here – too few to draw a robust conclusion – (ii) seems most likely, as the same concentration of

489    $Ge^{4+}$ in both crystals suggests that the Ge concentration in the two topaz crystals analyzed was

490    buffered through the precipitation of another Ge-bearing mineral phase in which $a_{Ge}^{S}$ <<1, such

491    as quartz, magnetite (e.g., Meng et al. 2017), hematite (e.g., Bernstein and Waychunas 1987),

492    cassiterite, or bixbyite (see summary of Höll et al. 2007). All of these phases have been found

493    associated with topaz rhyolite (Burt et al. 1982; Christiansen et al. 1984). In fact, as noted above,

494    a crystal of bixbyite was attached to one of the topaz samples analyzed here (Fig. 2) and quartz

495    was associated with both samples. Such buffering of $Ge^{4+}$ activity would inhibit the relative $Ge^{4+}$

496    content of the gas from increasing much during precipitation of nominally Ge-free phases.

497    Of the trace elements preferentially partitioning into the octahedral site, $Fe^{3+}$ has the greatest

498    abundance in the topaz crystals analyzed. The structural effects of $Fe^{3+}$ substitution diminish

22

499 further away from the cation (Table 4). These observations suggest primarily an effect of larger

500 ionic radius with little distortion of the structure. Formation of the $Fe^{3+}$ topaz component is likely

501 facilitated through the reaction of HF with the rhyolite, perhaps through the following reactions:

502 $\quad\quad$ $6HF$ (gas) + $Fe_2O_3$ (rhyolite) => $Fe_2F_6$ (gas) + $3H_2O$ (gas)

503 $\quad\quad$ $Si(OH)_4$ (gas) + $Fe_2F_6$ (gas) => $Fe_2SiO_4(F_2)$ (topaz) + $4HF$ (gas)

504 This topaz component may also be formed by -Si-O on the topaz surface reacting locally with

505 $Fe_2F_6$ in the gas. Although the Fe concentrations in the topaz crystals analyzed are high ($Fe^{3+}$:

506 $288\pm9$ ppm, Topaz-64; $158\pm5$ ppm, Topaz-7), they do not approach the more than 400 ppm of

507 $Fe^{3+}$ that has been observed in other topaz crystals (Breiter et al. 2013b). This suggests that when

508 this topaz formed, hematite was not yet precipitating and that the ferric iron content of the gas

509 continued to increase during formation of Fe-poor precipitates.

510 $\quad\quad$ The minor perturbation of the topaz structure by $Ga^{3+}$ and $Mn^{3+}$ substitution for $Al^{3+}$ (Table

511 4) suggests that topaz should be able to accommodate a significant amount of both. The much

512 lower concentration of $Ga^{3+}$ than $Fe^{3+}$ for both crystals analyzed suggests a lower $Ga^{3+}$

513 concentration in the rhyolite source, consistent with generally low Ga contents of felsic rocks

514 (e.g., Breiter et al. 2013b) and possibly coupled with lower partitioning of $Ga^{3+}$ into the gas. The

515 much lower $Mn^{3+}$ abundance relative to $Fe^{3+}$ is more difficult to explain since the presence of co-

516 existing bixbyite in Topaz-64 suggests a high load of Mn locally in the gas and that Topaz-64

517 was saturated in Mn. The low concentration of Mn in topaz at saturation with bixbyite may be

518 caused by the symmetry-lowering Jahn-Teller distortion of $Mn^{3+}$ in octahedral coordination (e.g.,

519 Halcrow 2013; Fridrichová et al. 2018). This Jahn-Teller distortion is likely incompatible with

520 the octahedral distortion inherent to the topaz structure caused by two shorter F apices and may

521 thus reduce the compatibility of Mn with the topaz structure, leading to a low solubility. In

522    comparison, beryl, formed under similar conditions in topaz rhyolite, but with a less distorted

523    $AlO_6$ octahedral site, can incorporate much higher Mn contents (e.g., Sardi and Heimann 2014;

524    over 300 ppm $Mn^{3+}$ in a beryl from Utah topaz rhyolite measured for this work). The low

525    solubility of Mn in topaz observed here is consistent with the typical low Mn contents for topaz

526    from anorogenic granite (Breiter et al. 2013b).

527        $Ti^{4+}$ substitution for Al in the octahedral site in topaz must be a coupled substitution in which

528    one of the apical $F^-$ (or $OH^-$) ions of the octahedron is replaced by $O^{2-}$ for charge balance. As

529    shown in Table 4, the cation-F bond in the octahedron is shorter than the cation-O bond. In a

530    fully relaxed structure, the substitution of $O^{2-}$ for $F^-$ (or $OH^-$) would thus lengthen the bond, but

531    the topaz structure does not permit this and the Ti-O bond in a F site will remain shortened. This

532    is effectively a Ti=O double bond, common in Ti-bearing phases (e.g., titanite, Speer and Gibbs

533    1976), which satisfies the increased bonding needs for $Ti^{4+}$ in that site.

534        In late-stage rhyolite melt $Ti^{4+}$ may be in 5-coordinated complexes with 4 bridging and one

535    non-bridging O bond (e.g., Ackerson et al. 2020) that are tightly bound and likely show little

536    solubility in the exsolving gas. This may account for the observation that Ti abundance is low in

537    the gas phase (e.g., Symonds and Reed 1993; Shevko et al. 2018). In spite of these complexities,

538    $Ti^{4+}$ contents are quite variable in topaz, and can reach 480 ppm (Gauzzi and Graça 2018),

539    suggesting that the Ti contents in the topaz studied here, had not reached saturation in $Ti^{4+}$

540    content.

541        Perhaps in spite of low Ti solubility in gas, locally, reaction of an HF-rich gas with Ti-

542    bearing rhyolitic glass, ilmenite (or hematite with an ilmenite component) could release $Ti^{4+}$ to

543    form a gaseous species such as $TiF_4$. This may produce the Ti topaz component through a

544    reaction such as:

545     $Si(OH)_4$ (gas) + $2TiF_4$ (gas) + $2H_2O$ (gas) = $Ti_2SiO_4(OO)$ (topaz) + 8HF (gas)
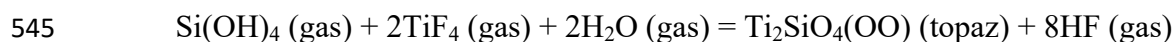
546

547                                     **IMPLICATIONS**

548     This work has demonstrated that synchrotron-based microbeam XAS studies on picogram

549     abundances of trace elements in single crystals can yield definitive information on their

550     oxidation states, site occupancy, and the local structural perturbations that they induce. It

551     documents the substitution of arsenic for silicon in a common silicate mineral. This work also

552     presents the first synchrotron-based Al EXAFS analysis of topaz. In addition to improving our

553     understanding of structural accommodation of trace elements in minerals, this work shows the

554     potential of using trace elements in minerals to constrain the compositional characteristics of

555     dilute gases involved in their formation and to gain insights into the gas-mediated processes that

556     lead to mineral precipitation and alteration in the shallow subvolcanic environment. This study

557     opens up new directions in the exploration of these processes.

568  98CH10886, respectively. Measurements supported by the Tender Energy Microspectroscopy

569  Consortium.

**REFERENCES CITED**

571  Ackerson, M.R., Cody, G.D. and Mysen, B.O. (2020) $^{29}$Si solid state NMR and Ti K-edge XAFS

572  pre-edge spectroscopy reveal complex behavior of Ti in silicate melts. Progress in Earth and

573  Planetary Science, 7, 14-25.

574  Agangi, A., Kamenetsky, V.S., Hofmann A., Przybylowicz, W. and Vladykin, N.V. (2014)

575  Crystallization of magmatic topaz and implications for Nb-Ta-W mineralization in F-rich

576  silicic melts – the Ary-Bulak ongonite massif. Lithos, 202, 317-330.

577  Alston, N.A. and West, J. (1928) The structure of topaz. Proceedings of the Royal Society A,

578  121, 358-367.

579  Bernstein, L. and Waychunas, G. (1987) Germanium crystal chemistry in hematite and goethite

580  from the Apex mine Utah, and some new data on germanium in aqueous solution and in

581  stottite. Geochimica et Cosmochimica Acta, 51, 623-630.

582  Bikun, J.V. (1980) Fluorine and lithophile element mineralization at Spor Mountain, Utah. U.S.

583  Department of Energy Open-File Report GJBX-225(80), 167-377.

584  Borisova, A.Y., Pokrovski, G.S., Pichavant, M., Freydier, R. and Candaudap, F. (2010) Arsenic

585  enrichment in hydrous peraluminous melts: insights from femtosecond laser ablation

586  inductively coupled plasma-quadrupole mass spectrometry, and in situ X-ray absorption fine

587  structure spectroscopy. American Mineralogist, 95, 1095-1104.

588  Bove, D.J., Mast, M.A., Dalton, J.B., Wright, W.G. and Yager, D.B. (2007) Major styles of

589  mineralization and hydrothermal alteration and related solid- and aqueous-phase geochemical

590  signatures. In: Integrated Investigations of Environmental Effects of Historical Mining in the

591        Animas River Watershed, San Juan County, Colorado, Church, S.E., von Guerard, Paul, and

592        Finger, S.E., Eds., U.S. Geological Survey Professional Paper 1651, 165-230.

593    Breiter, K., Gardenová, N., Kanický, V. and Vaculovič, T (2013a) Gallium and germanium

594        geochemistry during magmatic fractionation and post-magmatic alteration in different types

595        of granitoids: a case study from the Bohemian Massif (Czech Republic). Geologica

596        Carpathica, 64, 171-180.

597    Breiter, K., Gardenová, N., Vaculovič, T. and Kanický, V. (2013b) Topaz as an important host

598        for Ge in granites and greisens. Mineralogical Magazine, 77, 403–417.

599    Burt, D.M. and Sheridan, M.F. (1981) A model for the formation of uranium/lithophile element

600        deposits in fluorine-enriched volcanic rocks. American Association of Petroleum Geologists

601        Studies in Geology, 13, 99-109.

602    Burt, D.M., Sheridan, M.F., Bikun, J.V. and Christiansen, E.H. (1982) Topaz rhyolites;

603        distribution, origin, and significance for exploration. Economic Geology, 77, 1818–1836.

604    Christiansen, E.H., Bikun, J.V. and Burt, D.M. (1980) Petrology and geochemistry of topaz

605        rhyolites, western United States. U.S. Department of Energy Open-File Report GJBX-

606        225(80), 37-122.

607    Christiansen E.H., Bikun, J.V., Sheridan, M.F. and Burt, D.M. (1984). Geochemical evolution of

608        topaz rhyolites from the Thomas Range and Spor Mountain, Utah. American Mineralogist,

609        69, 223-236.

610    Citrin, P.H., Northrup, P., Atkins, R.M., Glodis, P.F., Niu, L., Marcus, M.A. and Jacobson, D.C.

611        (1998) Characterizing trace metal impurities in optical waveguide materials using X-ray

612        absorption. MRS Online Proceedings Library, 524, 251-257.

613  Dyar, M.D., Breves, E., Gunter, M., Lanzirotti, A., Tucker, J., Carey, C., Peel, S., Brown, E. and

614      Oberti, R. (2016) Use of multivariate analysis for synchrotron micro-XANES analysis of iron

615      valence state in amphiboles. American Mineralogist, 101, 1171-1189.

616  Farges, F., Brown, G.E., Jr. and Rehr, J.J. (1997) Ti K-edge XANES studies of Ti coordination

617      and disorder in oxide compounds: comparison between theory and experiment. Physical

618      Review B, 56, 1809-1819.

619  Fridrichová, J., Bacik, P., Ertl, A., Wildner, M., Dekan, J. and Miglierini, M. (2018) Jahn-Teller

620      distortion of $Mn^{3+}$-occupied octahedra in red beryl from Utah indicated by optical

621      spectroscopy. Journal of Molecular Structure, 1152, 79-86.

622  Gauzzi, T. and Graça, L. (2018) A cathodoluminscence-assisted LA-ICP-MS study of topaz from

623      different geological settings. Brazilian Journal of Geology, 48, 161-176.

624  Goad, B.E. and Černy, P. (1981) Peraluminous pegmatitic granites and their pegmatite aureoles

625      in the Winnipeg River district, southeastern Manitoba. Canadian Mineralogist, 19, 177-194.

626  Groat, L.A., Turner, D.J. and Evans, R.J. (2014) Gem deposits. Treatise on Geochemistry, 13,

627      595-622.

628  James-Smith, J., Cauzid, J., Testemale, D., Liu, W., Hazemann, J.-L., Proux, O., Etschmann, B.,

629      Philippot, P., Banks, D., Williams, P. and Brugger, J. (2010) Arsenic speciation in fluid

630      inclusions using microbeam X-ray absorption spectroscopy. American Mineralogist, 95,

631      921–932.

632  Kovalenko, V.L. and Kovalenko, N.I. (1976) Ongonites—subvolcanic analogues of rare metal

633      lithium-fluorine granites. Joint Soviet-Mongolian Scientific Research Geol. Expedition,

634      Transaction 15.

635    Halcrow, M.A. (2013) Jahn-Teller distortions in transition metal compounds, and their

636        importance in functional molecular and inorganic materials. Chemical Society Reviews, 42,

637        1784-1795.

638    Holfert, J. (1978) A field guide to topaz and associated minerals of Topaz Mountain, Utah. John

639        Holfert, Bountiful, UT.

640    Höll, R., Kling, M. and Schroll, E. (2007) Metallogenesis of germanium—a review. Ore

641        Geology Reviews, 30, 145–180.

642    Lindsey, D.A. (1977) Epithermal beryllium deposits in waterlaid tuff, western Utah. Economic

643        Geology, 72, 219-232.

644    Lindsey, D.A. (1982) Tertiary volcanic rocks and uranium in the Thomas Range and northern

645        Drum Mountains, Juab County, Utah. U.S. Geological Survey Professional Paper 1221.

646    Lipman, P.W., Christiansen, R.L. and Van Alstine, R.E. (1969) Retention of alkalis by calc-

647        alkalic rhyolites during crystallization and hydration. American Mineralogist, 54, 286-291.

648    Meng,Y., Hu, R., Huang, X. and Gao, J. (2017) Germanium in magnetite: a preliminary review.

649        Acta Geologica Sinica, 91, 711-726.

650    Maciag, B.J. and Brenan, J.M. (2020) Speciation of arsenic and antimony in basaltic magmas.

651        Geochimica et Cosmochimica Acta, 276, 198-218.

652
        Newville, M. (2008) Fundamentals of XAFS

653
        https://docs.xrayabsorption.org/tutorials/XAFS_Fundamentals.pdf

654    Northrup, P. (2019) The TES Beamline (8-BM) at NSLS-II: tender-energy spatially resolved X-

655        ray absorption spectroscopy and X-ray fluorescence imaging. Journal of Synchrotron

656        Radiation, 26, 2064-2074.

657    Northrup, P.A., Leinenweber, K., and Parise, J.B. (1994) The location of H in the high-pressure

658        synthetic $Al_2SiO_4(OH)_2$ topaz analogue. American Mineralogist, 79, 401-404.

659    Northrup, P.A. and Reeder, R.J. (1994) Evidence for the importance of growth-surface structure

660        to trace element incorporation in topaz. American Mineralogist, 79, 1167-1175.

661    Northrup, P.A., Lamble, G., Lee, J.-F. and Reeder, R.J. (1995). An XAFS study of arsenic

662        substitution for silicon in topaz $[Al_2SiO_4(F,OH)_2]$. 1995 Goldschmidt Conference Program

663        and Abstracts, 76.

664

    Northrup, P.A. and Reeder, R. J. (1995) Relationship between the structure and growth

665        morphology of topaz $[Al_2SiO_4(OH,F)_2]$ using the periodic bond chain method. Journal of

666        Crystal Growth, 156, 433-442.

667

    O'Bannon, E.F. III and Williams, Q. (2019) A $Cr^{3+}$ luminescence study of natural topaz

668        $Al_2SiO_4(F,OH)_2$ up to 60 GPa. American Mineralogist, 104, 1656–1662.

669    Pauling, L. (1928) The crystal structure of topaz. Proceedings of the National Academy of

670        Sciences, USA, 14, 603-606.

671

    Penfield, S.L. and Minor, J.C. (1894) On the chemical composition and related physical

672        properties of topaz. American Journal of Science, s3-47, 387-396.

673    Pokrovski, G.S., Zakirov, I.V., Roux, J., Testemale, D., Hazemann, J.L., Bychkov, A.Y. and

674        Golikova, G.V. (2002) Experimental study of arsenic speciation in vapor phase to 500°C:

675        implications for As transport and fractionation in low-density crustal fluids and volcanic

676        gases. Geochimica et Cosmochimica Acta, 70, 3453-3480.

677    Ravel, B. and Newville, M. (2005) ATHENA, ARTEMIS, HEPHAESTUS: data analysis for X-

678        ray absorption spectroscopy using IFEFFIT. Journal of Synchrotron Radiation, 12, 537-541.

679    Ribbe, P.H. and Gibbs, G.V. (1971) The crystal structure of topaz and its relation to physical

680        properties. American Mineralogist, 56, 24-30.

681    Roedder, E., and Stalder, H.A. (1988) "Pneumatolysis" and fluid-retention evidence for crystal

682        growth from a vapor phase. In: Fluid Inclusions, Santosh, M. ed. Geological Society of India,

683        M-11, 1-12.

684    Rossman, G.R. (2011) The color of topaz. In: Topaz: Perfect Cleavage, Clifford, J., Falster,

685        A.U., Hanson, S., Liebtrau, S., Neumeier, G. and Staebler, G., eds., Lithographie, 79-85.

686    Sardi, F. and Heimann, A. (2014) Pegmatitic beryl as indicator of melt evolution: example from

687        the Velasco District, Pampeana pegmatite province, Argentina, and review of worldwide

688        occurrences. Canadian Mineralogist, 52, 1-28.

689    Schott, S., Rager, H., Schürmann, K. and Taran, M. (2003) Spectroscopic study of natural gem

690        quality "Imperial" topazes from Ouro Preto, Brazil. European Journal of Mineralogy, 15,

691        701–706.

692    Shevko, E.P., Bortnikova, S.B, Abrosimova, N.A., Kamenetsky, V.S., Bortnikova, S.P.,

693        Panin, G.L. and Zelenski M. (2018) Trace elements and minerals in fumarolic sulfur: the case

694        of Ebeko Volcano, Kuriles. Geofluids, 2018, Article ID 4586363.

695
       Speer, J.A. and Gibbs, G.V. (1976) The crystal structure of synthetic titanite, $CaTiOSiO_4$, and

696
       the domain textures of natural titanites. American Mineralogist, 61, 238-247.

697
       Staatz, M.H. and Carr, W.J. (1964) Geology and mineral deposits of the Thomas and Dugway

698
       Ranges, Juab and Tooele Counties, Utah. U.S. Geological Survey Professional Paper 415.

699    Symonds, R.B. and Reed, M.H. (1993) Calculation of multicomponent chemical equilibria in

700        gas-solid-liquid systems: calculation methods, thermochemical data and applications to

31

701    studies of high-temperature volcanic gases with examples from Mount St. Helens. American

702    Journal of Science, 293, 758-864.

703  Testemale D., Pokrovski G. S. and Hazemann, J. L. (2011) Speciation of AsIII and AsV in

704    hydrothermal fluids by in situ X-ray absorption spectroscopy. European Journal of

705    Mineralogy, 23, 379-390.

706  Thomas, R. (1982) Ergebnisse der thermobarogeochemischen Untersuchungen an

707    Flüssigkeitseinschlüssen in Mineralen der postmagmatischen Zinn-Wolfram Mineralisation

708    des Erzgebirges. Freiberger Forschungshefte, 370.

709  Verweij, H. (1980) Melting and fining of arsenic-containing silicate glass batches. Ph.D. Thesis,

710    Technische Hogeschool Eindhoven. https://doi.org/10.6100/IR95983

711  Wasim, M., Zafar, W., Tufail, M., Arif, M., Daud, M. and Ahmad, A. (2011) Elemental analysis

712    of topaz from northern areas of Pakistan and assessment of induced radioactivity level after

713    neutron irradiation for color induction. Journal of Radioanalytical and Nuclear Chemistry,

714    287, 821–826.

715  Wyckoff, R.W.G. (1969) Crystal Structures, Vol. 4, 174.

716 **FIGURE CAPTIONS**

717 **FIGURE 1.** Partial view of the topaz crystal structure. Structure parameters from Wyckoff

718 (1969). (Rendering by Crystalmaker).

719 **FIGURE 2.** Side and front view of topaz crystal (Topaz-64) as mounted for analysis. Black

720 cubic crystal is bixbyite.

721 **FIGURE 3.** XANES region of the merged XAS spectra for each analyzed trace element in topaz

722 with reference spectra for determination of oxidation state. A) Arsenic data with $As^{1-}$ in orpiment

723 measured in fluorescence; $As^{3+}$ and $As^{5+}$ as sodium salts dissolved in water and dried onto

724 cellulose paper measured in transmission. B) Germanium data; inset shows Si XANES in topaz

725 for comparison. C) Iron data with $Fe^0$ foil measured in transmission; $Fe^{2+}$ in siderite measured in

726 fluorescence using a defocused beam; $Fe^{3+}$ in ferrihydrite precipitated on quartz measured in

727 fluorescence. D) Manganese data with $Mn^0$ foil measured in transmission; $Mn^{2+}$ sulfate

728 measured in fluorescence; $Mn^{3+}$ in $Mn_2O_3$ measured in fluorescence; and $Mn^{4+}$ pyrolusite

729 measured in fluorescence. E) Titanium data. F) Gallium data.

730 **FIGURE 4.** Fourier transform of Si and Al EXAFS data compared to calculated fits. This is

731 effectively the distribution of radial distance, R, of scatterers around the absorbing atom, except

732 distances are not corrected for phase shift.

733 **FIGURE 5.** Arsenic EXAFS data compared to fit for As in the tetrahedral site of topaz plotted

734 as: (a) R, as Fig. 4., (b) k, the measured EXAFS frequencies before Fourier transform, (c) q, the

735 back-transform of measured data calculated from the same range of R used for fitting, i.e.

736 Fourier filtered for direct comparison to model fit, (d) the real component of R, an indicator of fit

737 quality.

738 **FIGURE 6.** Germanium EXAFS data and fit in R (as Fig. 4) for Ge in the tetrahedral site.

739     **FIGURE 7.** EXAFS data and fit in R (as Fig. 4) for trace elements in the topaz octahedral site

740     (a) Fe, (b) Mn, (c) Ga, (d) Ti.

741

742 **TABLES**

743

744 **TABLE 1.** Measured trace element abundance for samples Topaz-64 and Topaz-7. Mass values

745 are calculated assuming a rectangular beam cross-section.

| Trace Element | Computed Sampling Depth (µm) | Mass of Topaz Analyzed (ng) | Concentration (ppm) | | Element Mass in Volume Analyze | |
|---|---|---|---|---|---|---|
| | | | Topaz-64 | Topaz-7 | Topaz-64 | Topaz-7 |
| As | 132 | 38 | 327(16) | 12.5(6) | 20(1) | 0.78(4) |
| Fe | 42 | 12 | 288(9) | 3.5(1) | 158(5) | 1.92(6) |
| Ga | 102 | 29 | 9.4(5) | 0.28(1) | 6.5(3) | 0.19(1) |
| Ge | 117 | 34 | 14.8(7) | 0.50(3) | 14.5(7) | 0.49(2) |
| Mn | 34 | 10 | 10(1) | 0.10(1) | 4.4(5) | 0.04(1) |
| Ti | 16 | 5 | 79(11) | 0.38(5) | 125(18) | 0.59(9) |

746

747

748 **Table 2.** Cation-to-cation single-scattering path lengths out to second neighbors for Si and Al in

749 fluor-topaz. Models are recalculated from crystallographic data (Northrup et al. 1994). Si and Al

750 fits are from EXAFS data (this study), with model paths of similar length grouped together. Fit

751 parameters: change in path length $\Delta R$, disorder parameter $\sigma^2$, and amplitude reduction $S0^2$;

752 degeneracy n is fixed. R-factor of Si fit is 0.087; Al, 0.025.

| Si(IV) Model | | Si(IV) from EXAFS fit | | | | | |
|---|---|---|---|---|---|---|---|
| Path | R (Å) | Shell | Path | n | $\Delta R$ (Å) | $\sigma^2$ (Å$^2$) | $S0^2$ |
| Si-O | 1.638(1) | 1 | Si-O | 4 | -.006(13) | .0003(23) | .97(9) |
| Si-O | 1.642(1) | | | | | | |
| Si-O | 1.642(1) | | | | | | |
| Si-O | 1.647(1) | | | | | | |
| | | | | | | | |
| Si-Al | 3.174(2) | 2 | Si-Al | 8 | -.009(26) | .0001(29) | .63(16) |
| Si-Al | 3.174(2) | | | | | | |
| Si-Al | 3.189(2) | | | | | | |
| Si-Al | 3.189(2) | | | | | | |
| Si-Al | 3.202(2) | | | | | | |
| Si-Al | 3.202(2) | | | | | | |
| Si-Al | 3.213(2) | | | | | | |
| Si-Al | 3.213(2) | | | | | | |

| Al(III) Model | | Al(III) from EXAFS fit | | | | | |
|---|---|---|---|---|---|---|---|
| Path | R (Å) | Shell | Path | n | $\Delta R$ (Å) | $\sigma^2$ (Å$^2$) | $S0^2$ |
| Al-F | 1.791(1) | 1 | Al-F | 2 | .003(11) | .002(2) | .73(8) |
| Al-F | 1.800(1) | 1 | Al-O | 4 | " | " | " |
| Al-O | 1.888(1) | | | | | | |
| Al-O | 1.895(1) | | | | | | |
| Al-O | 1.898(1) | | | | | | |
| Al-O | 1.899(1) | | | | | | |
| | | | | | | | |
| Al-Al | 2.810(2) | 2 | Al-Al | 2 | .03(4) | .002(6) | .43(25) |
| Al-Al | 2.839(2) | 2 | Al-Si | 4 | " | " | " |
| Al-Si | 3.174(2) | 2 | Al-Al | 2 | " | " | " |
| Al-Si | 3.189(2) | | | | | | |
| Al-Si | 3.202(2) | | | | | | |
| Al-Si | 3.213(2) | | | | | | |
| Al-Al | 3.427(2) | | | | | | |
| Al-Al | 3.427(2) | | | | | | |

753    **Table 3.** Tetrahedral EXAFS fits, with model Si path lengths generated by Artemis FEFF

754    calculation included for comparison. Fit parameters: change in path length $\Delta R$, disorder

755    parameter $\sigma^2$, and amplitude reduction $S0^2$; degeneracy n is fixed. R-factor of As fit is 0.021; Ge,

756    0.030.

| Si(IV) Model | | | As(V) | | | | | |
|---|---|---|---|---|---|---|---|---|
| Path | n | R (Å) | Shell | Path | n | $\Delta R$ (Å) | $\sigma^2$ (Å$^2$) | S0$^2$ |
| Si-O | 4 | 1.638-1.647 | 1 | As-O | 4 | .060(9) | .0010(19) | .83(14) |
| Si-Al | 8 | 3.174-3.213 | 2 | As-Al | 8 | .060(19) | .0001(24) | .78(34) |
| | | | | Ge(IV) | | | | |
| | | | 1 | Ge-O | 4 | .092(8) | -0.001(2) | .96(7) |

757

758    **Table 4.** EXAFS fits for octahedral ions, with model Al path lengths generated by Artemis FEFF

759    calculation included for comparison. Fit parameters: change in path length $\Delta R$, disorder

760    parameter $\sigma 2$, and amplitude reduction $S02$; degeneracy n is fixed. R-factor of Fe fit is 0.005; Ga

761    0.090; Mn 0.009; Ti 0.006.

| Al(III) Model | | | Fe(III) | | | | | |
|---|---|---|---|---|---|---|---|---|
| Path | n | R (Å) | Shell | Path | n | $\Delta R$ (Å) | $\sigma^2$ (Å$^2$) | S0$^2$ |
| Al-F | 2 | 1.791-1.800 | 1 | Fe-F | 2 | .086(6) | .00014(49) | 0.75(2) |
| Al-O | 4 | 1.888-1.899 | 1 | Fe-O | 4 | " | " | " |
| Al-Al | 2 | 2.810-2.839 | 2 | Fe-Al | 2 | .021(11) | -.0003(30) | 0.53(6) |
| Al-Si | 4 | 3.174-3.213 | 2 | Fe-Si | 4 | " | " | " |
| Al-Al | 2 | 3.427 | 2 | Fe-Al | 2 | " | " | " |
| | | | | Ga(III) | | | | |
| | | | 1 | Ga-F | 2 | .022(11) | .007(2) | .80(8) |
| | | | 1 | Ga-O | 4 | " | " | " |
| | | | | Mn(III) | | | | |

| 1 | Mn-F | 2 | .034(20) | -0.001(4) | .52(17) |
| 1 | Mn-O | 4 | " | " | " |

| | | | **Ti(IV)** | | |
| --- | --- | --- | --- | --- | --- |
| 1a | Ti-F | 2 | .042(24) | .0022(69) | .60(20) |
| 1b | Ti-O | 4 | .113(24) | .0022(69) | .60(20) |

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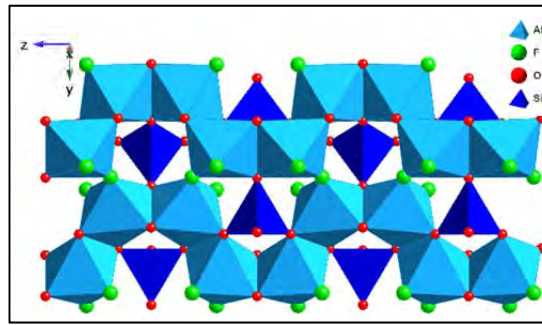
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764    **FIGURE 1.**

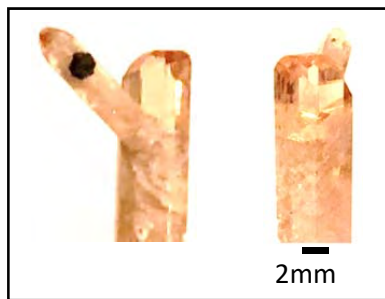765



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770    **FIGURE 2.**

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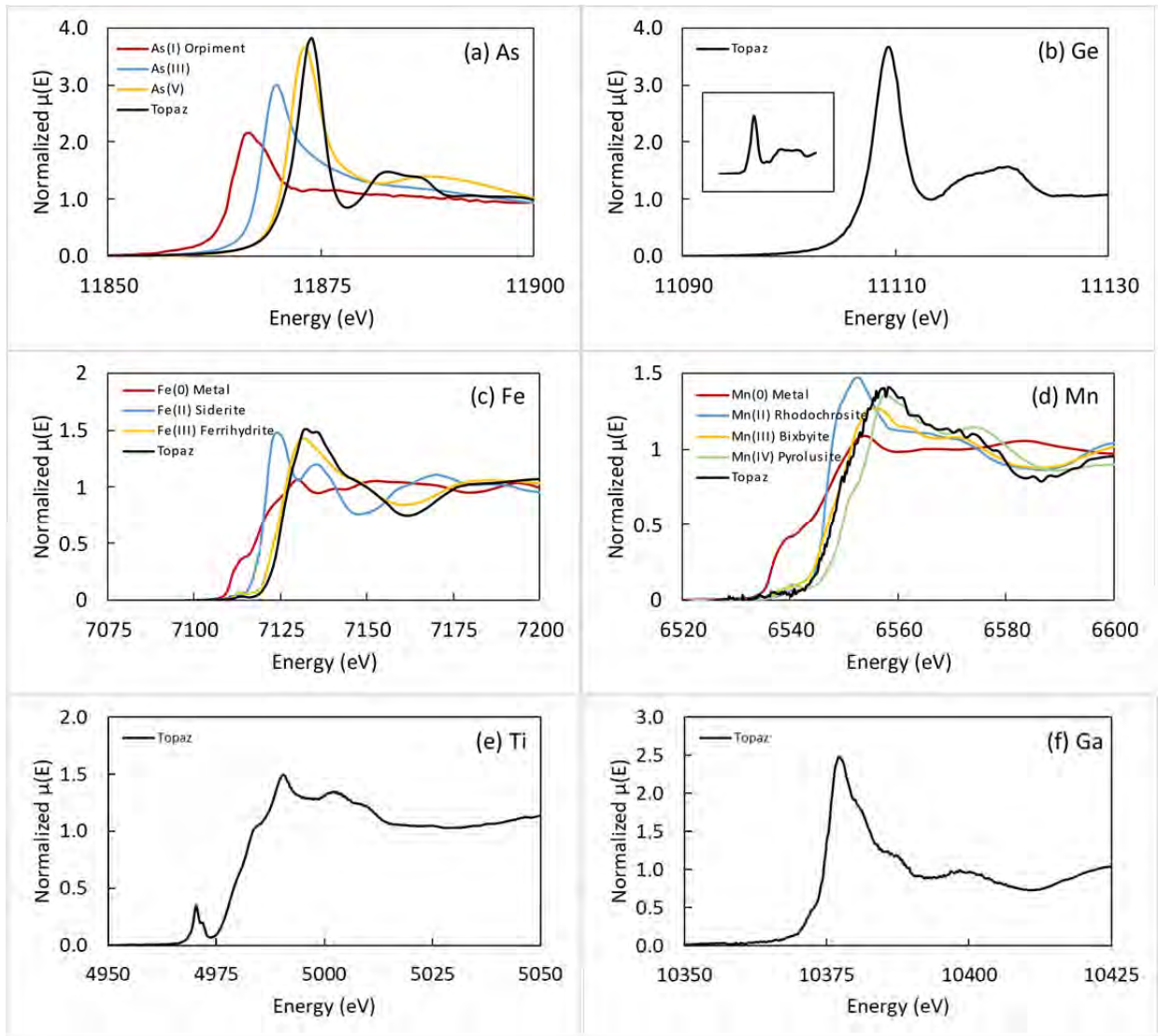


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782 **FIGURE 3.**
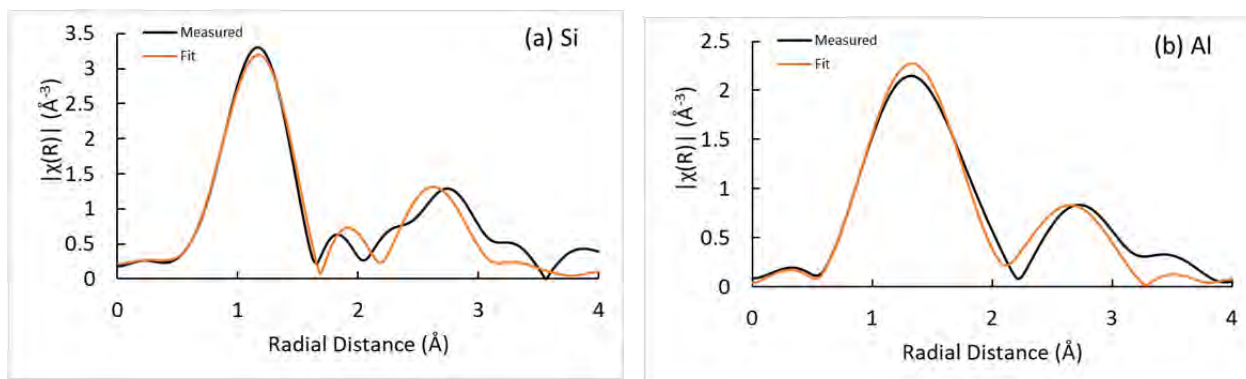


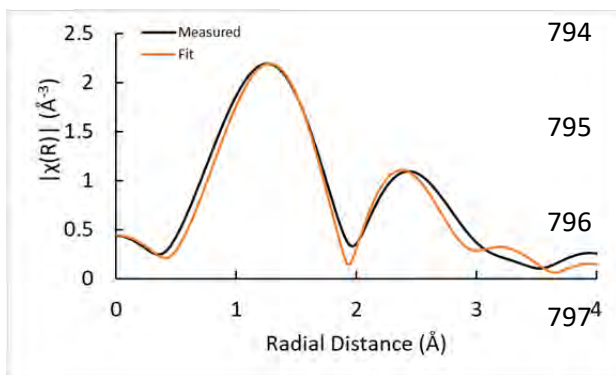783

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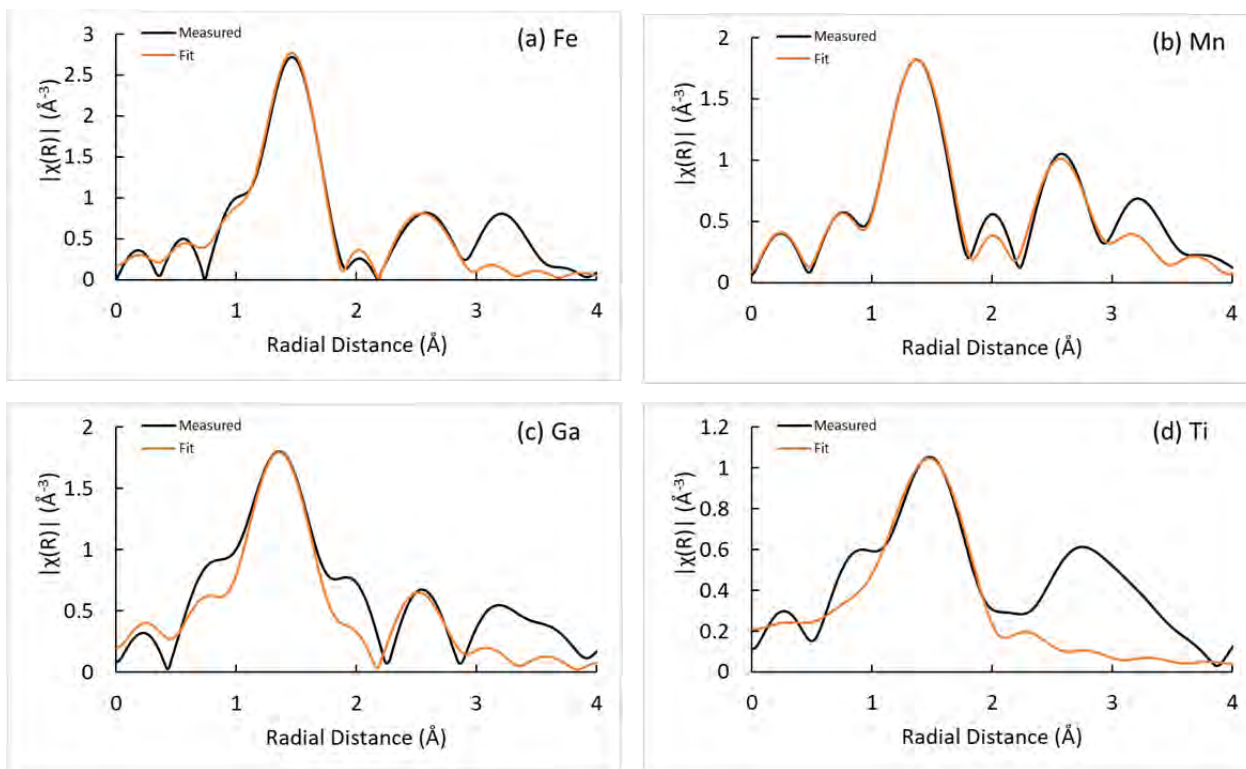
787    **FIGURE 4.**

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789    **FIGURE 5.**
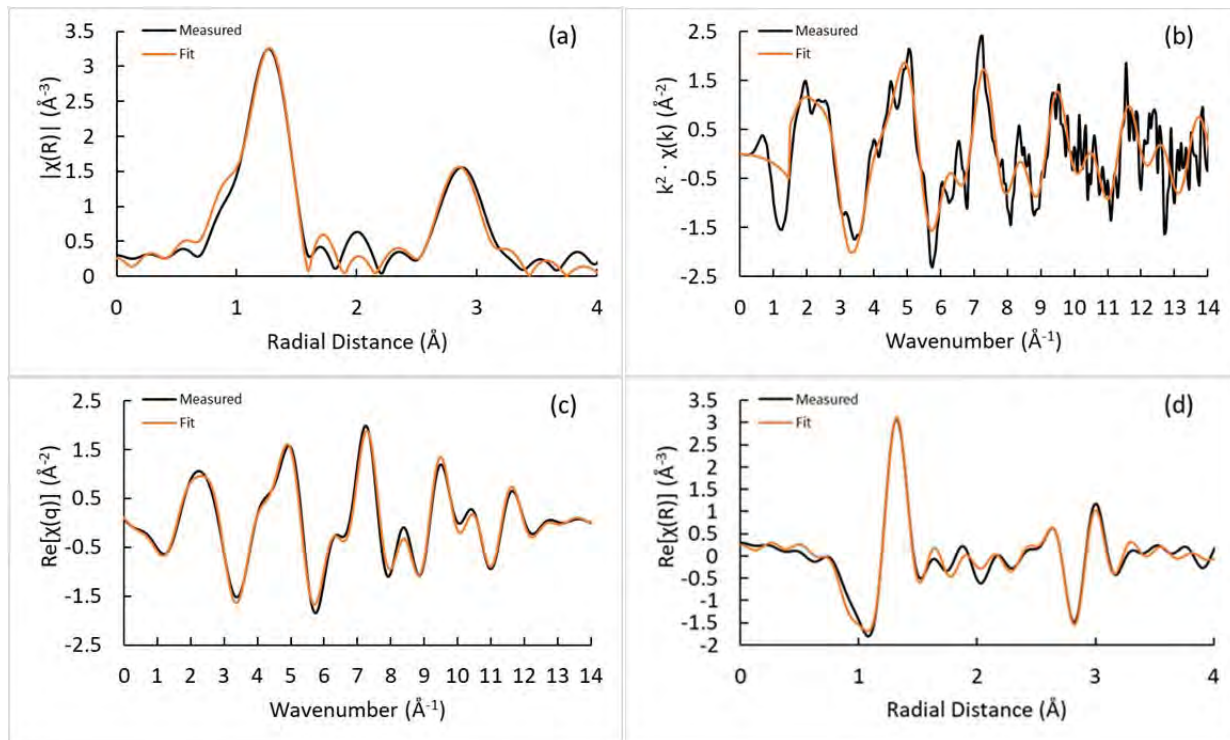
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793 **FIGURE 6.**



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799 **FIGURE 7.**



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